



#### P-CHANNEL ENHANCEMENT MODE MOSFET

#### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> max	I <sub>D</sub> max T <sub>A</sub> = +25°C
-20V	100mΩ @ V <sub>GS</sub> = -4.5V	-2.0A
	120mΩ @ V <sub>GS</sub> = -2.5V	-1.9A
	160mΩ @ V <sub>GS</sub> = -1.8V	-1.6A

#### **Description**

This MOSFET is designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

### **Applications**

- Motor Control
- Power Management Functions
- Backlighting

## **Features and Benefits**

- Low Input Capacitance
- · Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <a href="https://www.diodes.com/quality/product-definitions/">https://www.diodes.com/quality/product-definitions/</a>

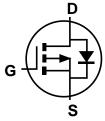
#### **Mechanical Data**

- Case: SOT323
- Case Material: Molded Plastic, "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals Connections: See Diagram Below
- Terminals: Finish—Matte Tin Annealed over Alloy 42 Leadframe.
   Solderable per MIL-STD-202, Method 208<sup>®</sup>
- Weight: 0.006 grams (Approximate)

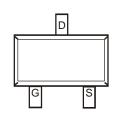




Top View



Internal Schematic



Top View

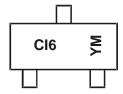
#### Ordering Information (Note 4)

Part Number	Case	Packaging
DMP2110UW-7	SOT323	3000/Tape & Reel
DMP2110UW-13	SOT323	10,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

### **Marking Information**



CI6 = Marking Code YM = Date Code Marking  $\overline{Y}$  = Year (ex: H = 2020) M = Month (ex: 9 = September)

Date Code Key

Year	2018	2019	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029
Code	F	G	Н		J	K	L	M	N	0	Р	R
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

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## **Maximum Ratings** (@ $T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage	V <sub>DSS</sub>	-20	V	
Gate-Source Voltage	V <sub>GSS</sub>	±12	V	
Continuous Drain Current (Note 6) V <sub>GS</sub> = -4.5V	I <sub>D</sub>	-2.0 -1.6	А	
Maximum Continuous Body Diode Forward Curre	nt (Note 6	Is	-0.9	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1	1%) (Note	Ірм	-15	Α

### **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	PD	0.49	W
Thermal Resistance, Junction to Ambient	RθJA	253	°C/W
Total Power Dissipation (Note 6)	PD	0.65	W
Thermal Resistance, Junction to Ambient	RθJA	192	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

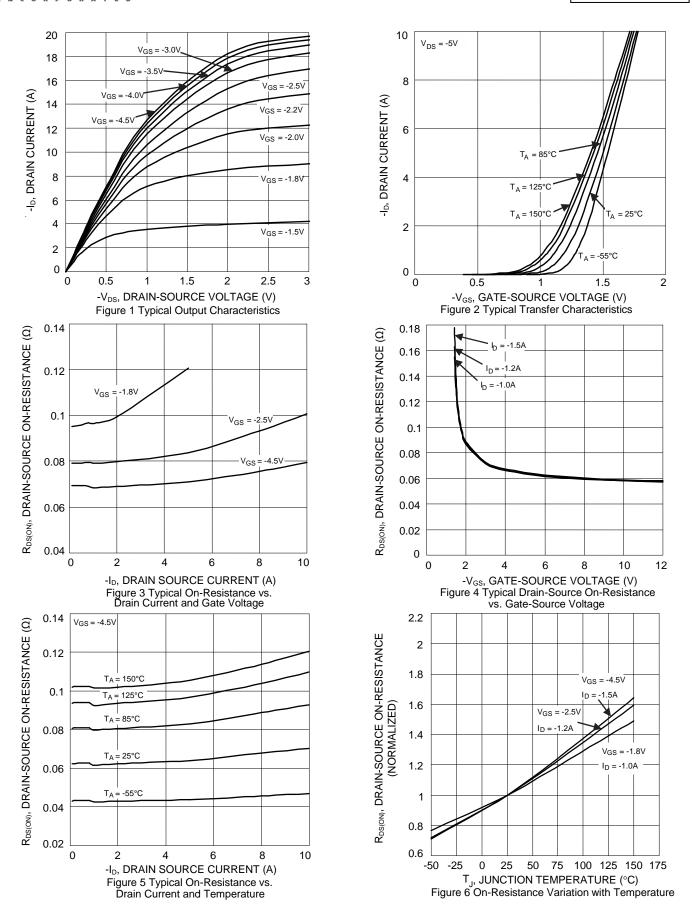
# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition		
OFF CHARACTERISTICS (Note 7)								
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-20	_	_	V	$V_{GS} = 0V, I_D = -250\mu A$		
Zero Gate Voltage Drain Current T <sub>J</sub> = +25°C	IDSS	_	_	-1.0	μΑ	V <sub>DS</sub> = -20V, V <sub>GS</sub> = 0V		
Gate-Source Leakage	I <sub>GSS</sub>	_	_	±100 ±800	nA	$V_{GS} = \pm 8V$ , $V_{DS} = 0V$ $V_{GS} = \pm 12V$ , $V_{DS} = 0V$		
ON CHARACTERISTICS (Note 7)		<u> </u>			<u>I</u>	1.00 =:=:, :B0 =:		
Gate Threshold Voltage	V <sub>GS(TH)</sub>	-0.4	_	-0.9	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$		
			63	100		V <sub>GS</sub> = -4.5V, I <sub>D</sub> = -1.5A		
Static Drain-Source On-Resistance	RDS(ON)	_	75	120	mΩ	V <sub>G</sub> S = -2.5V, I <sub>D</sub> = -1.2A		
			89	160		VGS = -1.8V, ID = -1A		
Diode Forward Voltage	V <sub>SD</sub>	_	-0.7	-1.0	V	V <sub>GS</sub> = 0V, I <sub>S</sub> = -1.0A		
DYNAMIC CHARACTERISTICS (Note 8)								
Input Capacitance	Ciss	_	443	1	pF			
Output Capacitance	Coss	_	59	1	pF	V <sub>DS</sub> = -6V, V <sub>GS</sub> = 0V f = 1.0MHz		
Reverse Transfer Capacitance	Crss	_	47	1	pF	1 = 1.011112		
Gate Resistance	Rg	_	8.5	_	Ω	$V_{GS} = 0V$ , $V_{DS} = 0V$ , $f = 1.0MHz$		
Total Gate Charge	Qg	_	6.0	_	nC			
Gate-Source Charge	Qgs	_	0.6	_	nC	V <sub>G</sub> S = -4.5V, V <sub>D</sub> S = -10V, I <sub>D</sub> = -		
Gate-Drain Charge	Qgd	_	1.8	_	nC			
Turn-On Delay Time	td(ON)	_	4.0	_	ns			
Turn-On Rise Time	t <sub>R</sub>	_	3.7	_	ns	V <sub>DS</sub> = -10V, V <sub>GS</sub> = -4.5V,		
Turn-Off Delay Time	tD(OFF)	_	24.5		ns	$R_L = 10\Omega$ , $R_G = 1.0\Omega$ , $I_D = -1A$		
Turn-Off Fall Time	tF	_	9.5	_	ns			
Reverse Recovery Time	t <sub>RR</sub>	_	8.3	_	ns	I <sub>F</sub> = -1.0A, di/dt = 100A/μs		
Reverse Recovery Charge	Q <sub>RR</sub>	_	2.0	_	nC	IF = -1.0A, di/dt = 100A/µs		

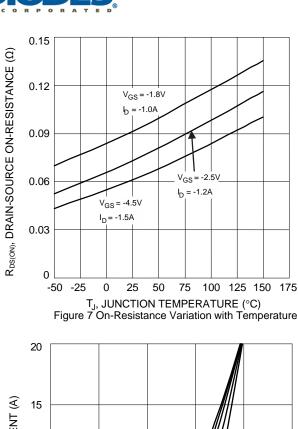
Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
 Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
 Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to product testing.

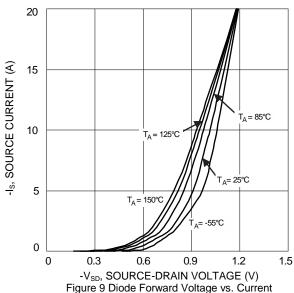
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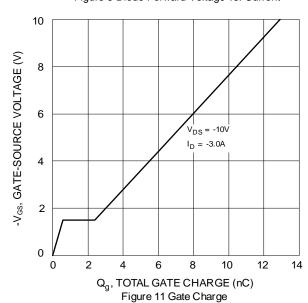












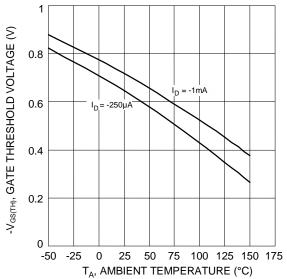
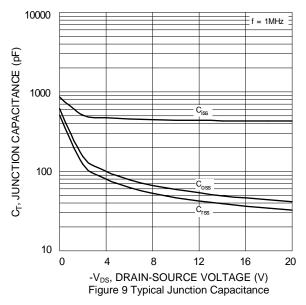
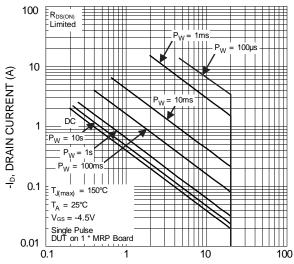


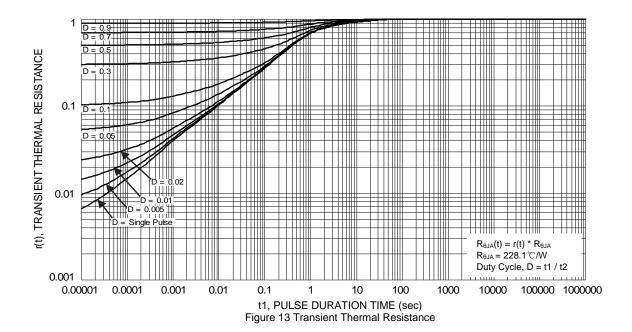
Figure 8 Gate Threshold Variation vs. Ambient Temperature





 ${ ext{-V}_{
m DS}}$ , DRAIN-SOURCE VOLTAGE (V) Figure 12 SOA, Safe Operation Area



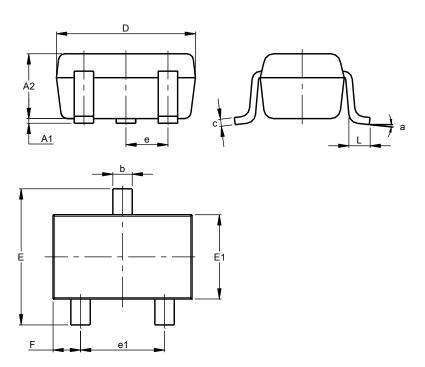




## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### **SOT323**

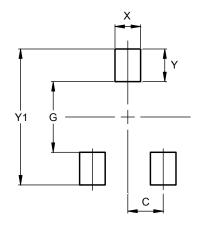


SOT323							
Dim	Min	Max	Тур				
A1	0.00	0.10	0.05				
A2	0.90	1.00	0.95				
b	0.25	0.40	0.30				
С	0.10	0.18	0.11				
D	1.80	2.20	2.15				
Е	2.00	2.20	2.10				
E1	1.15	1.35	1.30				
е	C	0.650 BSC					
e1	1.20	1.40	1.30				
F	0.375	0.475	0.425				
L	0.25	0.40	0.30				
а	0°	8°					
All Dimensions in mm							

## **Suggested Pad Layout**

 $\label{prop:lease} Please see \ http://www.diodes.com/package-outlines.html \ for \ the \ latest \ version.$ 

## SOT323



Dimensions	Value (in mm)				
С	0.650				
G	1.300				
Х	0.470				
Υ	0.600				
V1	2 500				



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